TOSHIBA SCHOTTKY BARRIER RECTIFIER STACK SCHOTTKY BARRIER TYPE

2GWJ2C42, U2GWJ2C42

SWITCHING TYPE POWER SUPPLY APPLICATION **CONVERTER & CHOPPER APPLICATION**

Average Output Rectified Current: IO=2A

Repetitive Peak Reverse Voltage $: V_{RRM} = 40V$

Low Switching Losses and Output Noise.

POLARITY MARKING Lot Number $\square\square$ —Month (Starting from Alphabet A) 2GWJ2 Year (Last Number of the Christian Era)

MAXIMUM RATINGS

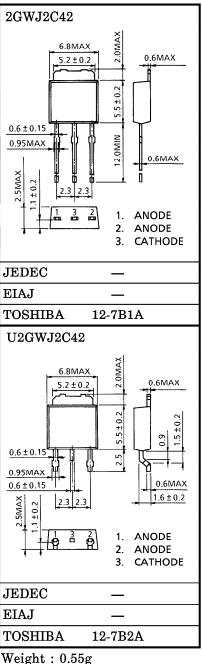
CHARACTERISTIC	SYMBOL	RATING	UNIT	
Repetitive Peak Reverse Voltage	v_{RRM}	40	V	
Average Output Rectified Current	I_{O}	2	Α	
Peak One Cycle Surge Forward Current (Sine Wave) IFSM	T	15 (50Hz)	A	
	16.5 (60Hz)	A		
Junction Temperature	$T_{ m j}$	-40~125	$^{\circ}\mathrm{C}$	
Storage Temperature Range	$ m T_{stg}$	-40~150	$^{\circ}\mathrm{C}$	

ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	TYP.	MAX.	UNIT
Peak Forward Voltage (Note 1)	$v_{ m FM}$	I _{FM} =1.0A	1	0.55	V
Repetitive Peak Reverse Current (Note 1)	IRRM	$V_{ m RRM}$ =40V	_	1.0	mA
Junction Capacitance (Note 1)	c_j	$V_R = 10V,$ $f = 1MHz$	45	_	pF
Thermal Resistance (Junction to Case)	R _{th (j-c)}	DC	_	8	°C/W
Thermal Resistance (junction to Ambient)	R _{th (j-a)}	DC (250mm * 0.8mm Ceramic)	_	125	°C/W

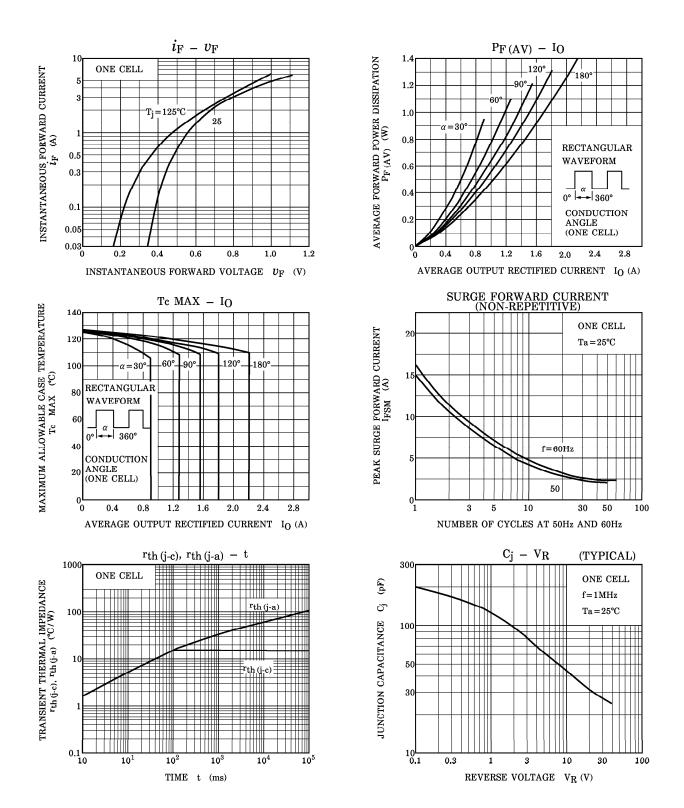
Note 1: A value of one cell.

Unit in mm



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